Vishay Siliconix

# Low Voltage, Dual Supply, Low Ron, Quad SPST Analog Switches

## **DESCRIPTION**

The DG9424, DG9425, DG9426 are low voltage precision monolithic quad single-pole-single-throw analog switches.

Using BiCMOS wafer fabrication technology allows the DG9424, DG9425, DG9426 to operate on single and dual supplies. Single supply voltage ranges from 3 V to 12 V while dual supply operation is recommended with  $\pm$  3 V to  $\pm$  6 V.

Combining high speed ( $t_{ON}$ : 42 ns), flat  $R_{DS(on)}$  over the analog signal range ( $\Omega$ ), minimal insertion lose (-3 dB at 190 MHz), and excellent crosstalk and off-isolation performance, the DG9424, DG9425, DG9426 are ideally suited for audio and video signal switching.

The DG9424 and DG9425 respond to opposite control logic as shown in the truth table. The DG9426 has two normally open and two normally closed switches.

#### **FEATURES**

- 2.7 V thru 12 V single supply or ± 3 thru ± 6 dual supply
- On-resistance  $R_{DS(on)}$ : 1.7  $\Omega$
- Fast switching ton: 42 ns
  - t<sub>OFF</sub>: 28 ns
- TTL, CMOS compatible
- Low leakage: 0.2 nA
- 2000 V ESD protection

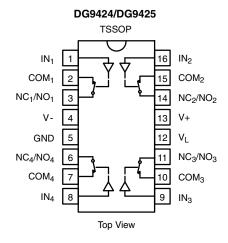
#### **BENEFITS**

- Widest dynamic range
- · Low signal errors and distortion
- Break-before-make switching action
- Simple interfacing

#### **APPLICATIONS**

- · Automatic test equipment
- · Data acquisition systems
- · Communication systems
- ADC systems
- xDSL and PBX / PABX
- · Audio signal routing

### **FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION**

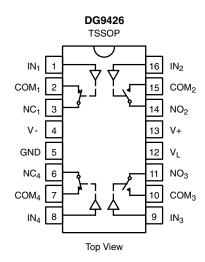


TRUTH TABLE						
LOGIC	DG9424	DG9425				
0	OFF	ON				
1	ON	OFF				



Vishay Siliconix

## **FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION**



TRUTH TABLE						
LOGIC	SW <sub>1</sub> , SW <sub>4</sub>	SW <sub>2</sub> , SW <sub>3</sub>				
0	ON	OFF				
1	OFF	ON				

ORDERING INFORMATION						
TEMP. RANGE	PACKAGE	PART NUMBER				
		DG9424DQ-T1-E3				
-40 °C to +85 °C	16-Pin TSSOP	DG9425DQ-T1-E3				
		DG9426DQ-T1-E3				

ABSOLUTE MAXIMUM RATINGS								
PARAMETER		LIMIT	UNIT					
V+ to V-		-0.3 to +13						
GND to V-		7	V					
V <sub>L</sub>		(GND - 0.3) to (V+) + 0.3	V					
IN, COM, NC, NO <sup>a</sup>		(V-) - 0.3 to (V+) + 0.3						
Continuous Current (NO, NC, COM Pins)		100	A					
Peak Current, S or D (Pulsed 1 ms, 10 % Duty Cycle)		200	mA					
Storage Temperature		-65 to +150	°C					
Power Dissipation (Package) b	16-Pin TSSOP <sup>c</sup>	450	mW					
Thermal Resistance b	10-PIII 1550P °	178	°C/W					

#### Notes

- a. Signals on NC, NO, COM or IN exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- b. All leads welded or soldered to PC board.
- c. Derate 7 mW/°C above 25 °C.



Vishay Siliconix

PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED	TEMP. b	LIMITS -40 °C to +85 °C			UNIT
		V+ = 12 V, V- = 0 V $V_L = 5 V, V_{IN} = 2.4 V, 0.8 V f$		MIN. d	TYP. c	MAX. d	· · · · ·
Analog Switch							
Analog Signal Range <sup>e</sup>	V <sub>ANALOG</sub>		Full	0	-	12	V
On-Resistance	R <sub>ON</sub>	V+ = 10.8 V, V- = 0 V	Room	ı	1.8	3	Ω
On-nesistance	TION	$I_{NO}$ , $I_{NC} = 50$ mA, $V_{COM} = 2 \text{ V} / 9 \text{ V}$	Full	-	-	4	52
Digital Control							
Input Current	I <sub>INL</sub> or I <sub>INH</sub>		Full	-1	0.01	1	μΑ
Dynamic Characteristics							
Turn-On Time <sup>e</sup>	t <sub>ON</sub>		Room	-	42	57	
Turn-On Time	ON	$R_L = 300 \ \Omega, \ C_L = 35 \ pF$	Full	ı	-	65	
Turn-Off Time <sup>e</sup>	$V_{NO}$ , $V_{NC} = 5$ V, see fig. 2	Room	-	28	42	ns	
Turr-Oil Time	t <sub>OFF</sub>		Full	ı	-	44	
Break-Before-Make Time Delay <sup>e</sup>	t <sub>D</sub>	DG9426 only, $V_{NO}$ , $V_{NC}$ = 5 V $R_L$ = 300 $\Omega$ , $C_L$ = 35 pF	Room	2	-	-	
Charge Injection e	$Q_{INJ}$	$V_g=0~V,~R_g=0~\Omega,~C_L=1~nF$	Room	-	38	-	рС
Off-Isolation e	OIRR	$R_L = 50 \Omega, C_L = 5 pF$	Room	ı	-56	-	dB
Channel-to-Channel Crosstalk e	X <sub>TALK</sub>	f = 1 MHz	Room	-	-77	-	ив
NO, NC Off Capacitance e	C <sub>NO(off)</sub>	f = 1 MHz	Room	_	49	-	pF
NO, NO OII Capacitance	C <sub>NC(off)</sub>		Hoom				
COM Off Capacitance e	C <sub>COM(off)</sub>	1 = 1 WILLS	Room	ı	37	-	ρı
Channel On Capacitance e	C <sub>COM(on)</sub>		Room	1	89	-	
Power Supplies							
Positive Supply Current	l+		Room	-	0.02	1	
Positive Supply Current	1+		Full	-	-	5	- μΑ
Nagativa Cumply Cumpant			Room	-1	-0.002	-	
Negative Supply Current	I-	$V_{IN} = 0$ or $V_L$	Full	-5	-	-	
Logio Supply Current	IL		Room	-	0.002	1	
Logic Supply Current			Full	-	-	5	
Ground Current	L		Room	-1	-0.002	-	
Ground Current	I <sub>GND</sub>		Full	-5	-	-	



Vishay Siliconix

PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED	TEMP.b	LIMITS -40 °C to +85 °C			UNIT
		V+ = 5 V, V- = 5 V $V_L = 5 V, V_{IN} = 2.4 V, 0.8 V^f$		MIN. d	TYP. °	MAX. d	
Analog Switch							
Analog Signal Range <sup>e</sup>	V <sub>ANALOG</sub>		Full	-5		5	V
On-Resistance	R <sub>ON</sub>	V+ = 4.5 V, V- = -4.5 V	Room	-	2	3.3	Ω
	5	$I_{NO}$ , $I_{NC} = 50$ mA, $V_{NO}$ , $V_{COM} = \pm 3.5$ V	Full	-	-	4.3	
	I <sub>NO(off)</sub>		Room	-1	-	1	
Switch Off Leakage Current	I <sub>NC(off)</sub>	V+ = 5.5 V, V- = -5.5 V	Full	-10	=	10	
Ownor on Lounage Garrent	I <sub>COM(off)</sub>	$V_{COM} = \pm 4.5 \text{ V}, V_{NO}, V_{NC} = \pm 4.5 \text{ V}$	Room	-1	-	1	nA
	'COM(OII)		Full	-10		10	.,,
Channel On Leakage Current	I <sub>COM(on)</sub>	V+ = 5.5 V, V- = -5.5 V,	Room	-1	-	1	
Chainer on Leakage Current	ICOM(on)	$V_{NO}$ , $V_{NC} = V_{COM} = \pm 4.5 \text{ V}$	Full	-10	-	10	
Digital Control							
Input Current <sup>a</sup>	I <sub>INL</sub> or I <sub>INH</sub>		Full	-1	0.05	1	μΑ
Dynamic Characteristics							
Turn-On Time <sup>e</sup>	+	$R_L = 300 \ \Omega, \ C_L = 35 \ pF$ $V_{NO}, \ V_{NC} = \pm 3.5 \ V, \ see \ fig. \ 2$	Room	-	48	67	ns
Turn-On Time 9	t <sub>ON</sub>		Full	-	-	81	
T 0"T' 0	+		Room	-	34	57	
Turn-Off Time <sup>e</sup>	t <sub>OFF</sub>		Full	-	-	67	
Break-Before-Make Time Delay <sup>e</sup>	t <sub>D</sub>	DG9426 only, $V_{NO}$ , $V_{NC}$ = 3.5 V $R_L$ = 300 $\Omega$ , $C_L$ = 35 pF	Room	2	-	-	
Charge Injection e	$Q_{INJ}$	$V_g$ = 0 V, $R_g$ = 0 $\Omega$ , $C_L$ = 1 nF	Room	-	112	-	рC
Off Isolation <sup>e</sup>	OIRR	$R_1 = 50 \Omega, C_1 = 5 pF, f = 1 MHz$	Room	-	-56	-	dB
Channel-to-Channel Crosstalk e	X <sub>TALK</sub>	$n_L = 30.22, O_L = 3.61, T = 1.101112$	Room	=	-82	-	uБ
Source Off Capacitance e	$C_{NO(off)} \ C_{NC(off)}$		Room	-	38	-	
Drain Off Capacitance e	C <sub>COM(off)</sub>	f = 1 MHz	Room	-	38	-	pF
Channel On Capacitance e	C <sub>COM(on)</sub>		Room	-	89	-	
Power Supplies							
Positive Supply Current e	I+		Room	-	0.03	1	
Positive Supply Current •	1.5		Full	-	-	5	
Negative Supply Current <sup>e</sup>	Į-		Room	-1	-0.002	-	
· · ·		$V_{IN} = 0 \text{ or } V_L$	Full	-5	-	-	μΑ
Logic Supply Current <sup>e</sup>	ال		Room	-	0.002	1	
			Full	-	-	5	
Ground Current e	I <sub>GND</sub>		Room	-1	-0.002	-	
around current			Full	-5	-	-	



Vishay Siliconix

SPECIFICATIONS a Single	e Supply 5	V					
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED	TEMP.b	LIMITS -40 °C to +85 °C			UNIT
		V+ = 5 V, $V- = 0 VV_L = 5 V, V_{IN} = 2.4 V, 0.8 V f$		MIN. d	TYP. c	MAX. d	
Analog Switch							
Analog Signal Range <sup>e</sup>	V <sub>ANALOG</sub>		Full	-	-	5	V
On-Resistance e	R <sub>ON</sub>	$V+ = 4.5 \text{ V}, I_{NO}, I_{NC} = 50 \text{ mA},$	Room	-	3.4	4.8	Ω
On-nesistance	PON	VCOM = 1 V, 3.5 V	Full	-	-	5.8	22
Dynamic Characteristics							
Turn-On Time <sup>e</sup>	+		Room	-	71	86	
rum-on time °	t <sub>ON</sub>	$R_L = 300 \Omega, C_L = 35 pF$	Hot	-	-	106	ns
Turn-Off Time e	V <sub>NO</sub> , V <sub>NC</sub>	$V_{NO}$ , $V_{NC} = 3.5 \text{ V}$ , see fig. 2	Room	-	37	51	
rum-on nine °			Hot	-	-	56	
Break-Before-Make Time Delay <sup>e</sup>	t <sub>D</sub>	DG9426 only, $V_{NO}$ , $V_{NC}$ = 3.5 V $R_L$ = 300 $\Omega$ , $C_L$ = 35 pF	Room	5	-	-	
Charge Injection <sup>e</sup>	Q <sub>INJ</sub>	$V_g = 0 \text{ V}, \text{ R}_g = 0 \Omega, \text{ C}_L = 1 \text{ nF}$	Room	-	10	-	рС
Power Supplies							
Docitive Cumply Current 6			Room	-	0.02	1	
Positive Supply Current <sup>e</sup>	I+		Hot	-	-	5	
Negative Cumply Cumpet 6	I-		Room	-1	-0.002	-	
Negative Supply Current <sup>e</sup>	I-		Hot	-5	-	-	
Logio Supply Current 6	I.	$V_{IN} = 0$ or $V_L$	Room	-	0.002	1	μA
Logic Supply Current <sup>e</sup>	IL		Hot	ı	-	5	
Ground Current <sup>e</sup>	1		Room	-1	-0.002	-	
Ground Current •	$I_{GND}$		Hot	-5	-	-	



Vishay Siliconix

SPECIFICATIONS <sup>a</sup> Single Supply 3 V							
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED	TEMP.b	LIMITS -40 °C to +85 °C			UNIT
		V+ = 3 V, V- = 0 V $V_L = 3 V, V_{IN} = 2.4 V, 0.4 V f$		MIN. d	TYP. c	MAX. d	
Analog Switch							
Analog Signal Range e	V <sub>ANALOG</sub>		Full	0	ı	3	V
On-Resistance	R <sub>ON</sub>	V+ = 2.7 V, V- = 0 V	Room	-	8	13.8	Ω
OII-Nesistance	HON	$I_{NO}$ , $I_{NC} = 5$ mA, $V_{COM} = 0.5$ V, 2.2 V	Full	-	-	15.1	52
	I <sub>NO(off)</sub>		Room	-1	-	1	
Switch Off Leakage Current <sup>a</sup>	I <sub>NC(off)</sub>	V+ = 3.3 V, V- = 0 V	Full	-10	-	10	
Switch On Leakage Current "	_	$V_{COM} = 0.3 \text{ V}, 3 \text{ V}, V_{NO}, V_{NC} = 3, 0.3 \text{ V}$	Room	-1	-	1	nA
	ICOM(off)		Full	-10	-	10	
Channel On Leakage Current 3	1	V+ = 3.3 V, V- = 0 V,	Room	-1	-	1	
Channel On Leakage Current <sup>a</sup>	I <sub>COM(on)</sub>	$V_{NO}, V_{NC} = V_{COM} = 0.3 \text{ V}, 3 \text{ V}$	Full	-10	-	10	
Digital Control <sup>e</sup>							
Input Current	I <sub>INL</sub> or I <sub>INH</sub>		Full	-1	0.005	1	μΑ
Dynamic Characteristics							
Turn-On Time	t <sub>ON</sub>		Room	-	140	163	
Turn-On Time		$R_L = 300 \Omega, C_L = 35 pF$	Full	-	ı	193	
Turn-Off Time	t	$V_{NO}$ , $V_{NC} = 1.5 \text{ V}$ , see fig. 2	Room	-	65	80	ns
Turn-On Time	t <sub>OFF</sub>		Full	-	ı	89	
Break-Before-Make Time Delay	t <sub>D</sub>	DG9426 only, $V_{NO}$ , $V_{NC}$ = 1.5 V $R_L$ = 300 $\Omega$ , $C_L$ = 35 pF	Room	5			
Charge Injection <sup>e</sup>	$Q_{INJ}$	$V_g$ = 0 V, $R_g$ = 0 $\Omega$ , $C_L$ = 1 nF	Room	-	15	-	рС
Off Isolation e	OIRR	$R_L = 50 \Omega, C_L = 5 pF$	Room	=	-56	-	dB
Channel-to-Channel Crosstalk e	X <sub>TALK</sub>	f = 1 MHz	Room	=	-80	-	αв
Source Off Capacitance e	C <sub>NO(off)</sub>		Room	_	53		
Source On Gapacitance	C <sub>NC(off)</sub>	f = 1 MHz	noon				pΕ
Drain Off Capacitance e	C <sub>COM(off)</sub>	I = I IVIDZ	Room	-	42	-	pF

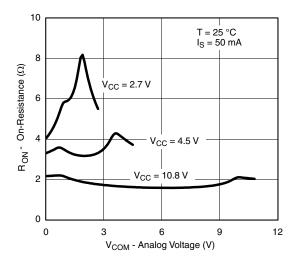
#### **Notes**

- a. Leakage parameters are guaranteed by worst case test conditions and not subject to production test.
- b. Room = 25 °C, Full = As determined by the operating temperature suffix.
- c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
- d. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this datasheet.
- e. Guaranteed by design, not subject to production test.
- f.  $V_{IN}$  = Input voltage to perform proper function.

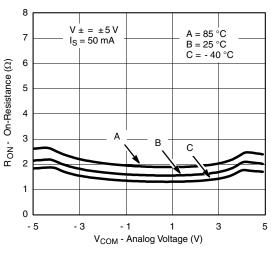
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



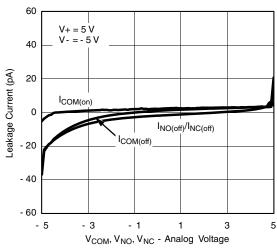
# TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



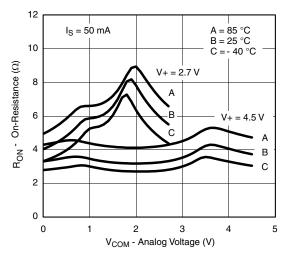
RON vs. VCOM and Supply Voltage



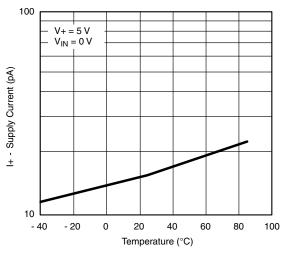
R<sub>ON</sub> vs. Analog Voltage and Temperature



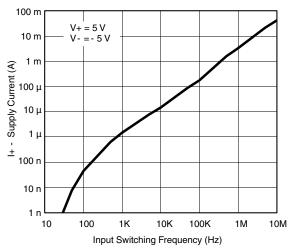
Leakage Current vs. Analog Voltage



R<sub>ON</sub> vs. Analog Voltage and Temperature



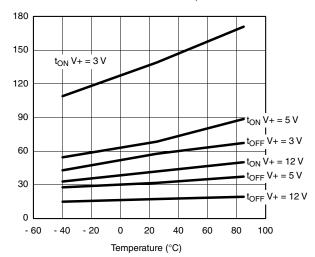
Supply Current vs. Temperature



**Switching Current vs. Input Switching Frequency** 

Vishay Siliconix

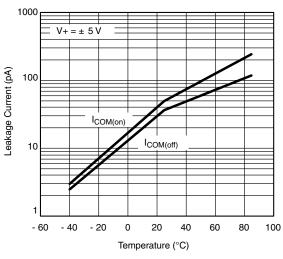
# TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

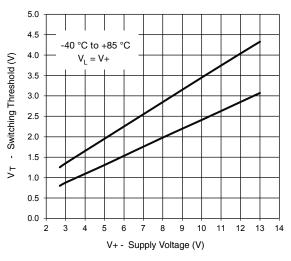


120  $V_{SUPPLY} = \pm 5 V$ 100 80 60  $t_{ON} V_S = -3.5 V$  $t_{ON} V_{S} = 3.5 V$ 40  $t_{OFF} V_S = -3.5 V$  $t_{OFF} V_S = 3.5 V$ 20 - 60 - 40 - 20 0 20 40 60 80 100 Temperature (°C)

Switching Time vs. Temperature and Single Supply Voltage

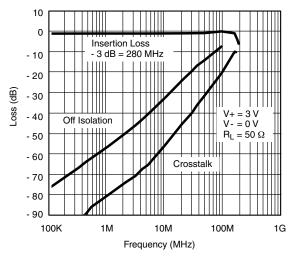
Switching Time vs. Temperature and Dual Supply Voltage





Leakage Current vs. Temperature

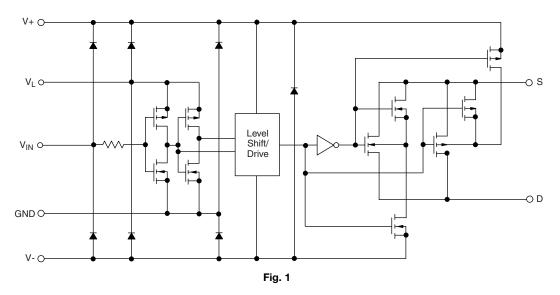
Switching Threshold vs. Supply Voltage



Insertion Loss, Off Isolation and Crosstalk vs. Frequency



# **SCHEMATIC DIAGRAM** (typical channel)



## **TEST CIRCUITS**

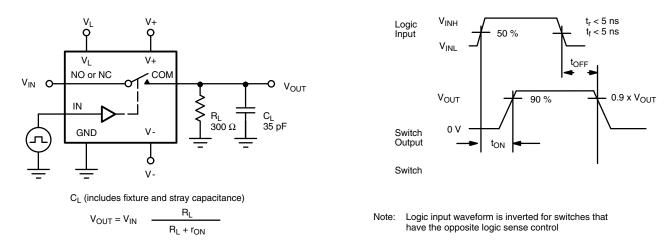


Fig. 2 - Switching Time

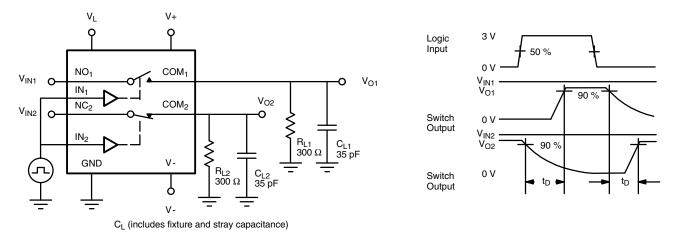


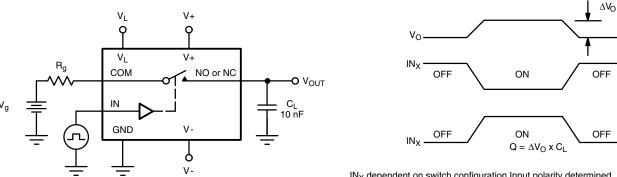
Fig. 3 - Break-Before-Make (DG9426)

ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

 $V_{IN} = 0 - V +$ 

# Vishay Siliconix

## **TEST CIRCUITS**



 $\ensuremath{\mathsf{IN}_{\mathsf{X}}}$  dependent on switch configuration Input polarity determined by sense of switch.

Fig. 4 - Charge Injection

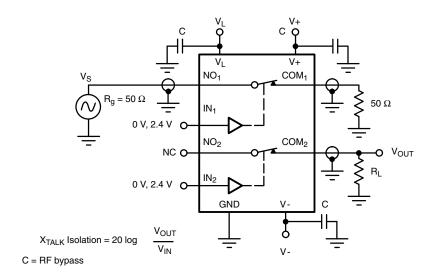


Fig. 5 - Crosstalk

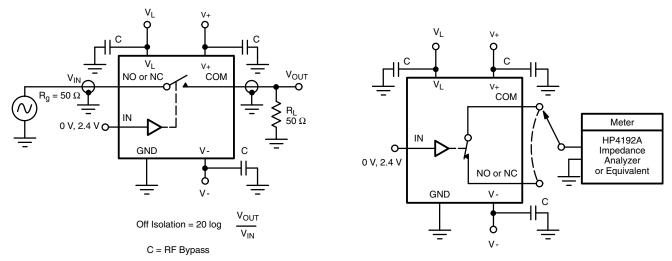


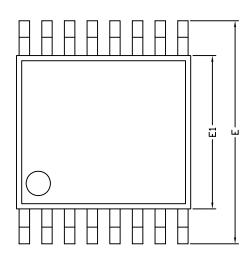
Fig. 6 - Off-Isolation

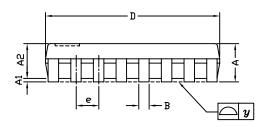
Fig. 7 - Source / Drain Capacitances

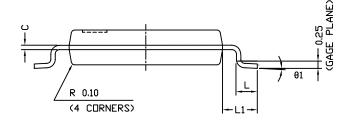
Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see <a href="https://www.vishay.com/ppg271807">www.vishay.com/ppg271807</a>.



**TSSOP: 16-LEAD** 







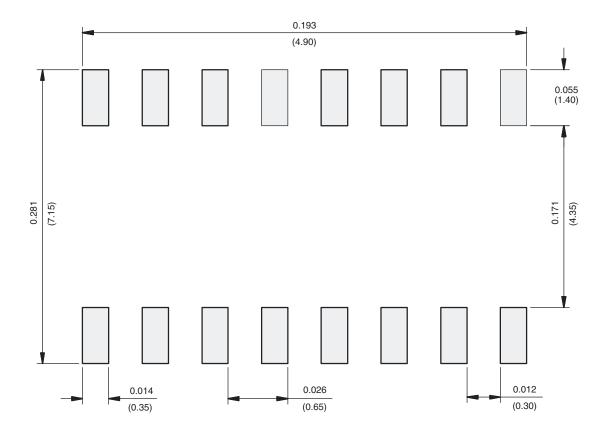
	DIN	MENSIONS IN MILLIMETER	RS
Symbols	Min	Nom	Max
А	-	1.10	1.20
A1	0.05	0.10	0.15
A2	-	1.00	1.05
В	0.22	0.28	0.38
С	-	0.127	-
D	4.90	5.00	5.10
E	6.10	6.40	6.70
E1	4.30	4.40	4.50
е	-	0.65	-
L	0.50	0.60	0.70
L1	0.90	1.00	1.10
у	-	-	0.10
θ1	0°	3°	6°
FCN: S-61920-Rev. D. 23-	Oct-06		

DWG: 5624

Document Number: 74417 www.vishay.com 23-Oct-06



## **RECOMMENDED MINIMUM PAD FOR TSSOP-16**



Recommended Minimum Pads Dimensions in inches (mm)



# **Legal Disclaimer Notice**

Vishay

# **Disclaimer**

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.